



Agilent HLMP-SL11, HLMP-RL11, HLMP-SD11, HLMP-RD11, HLMP-RB11, HLMP-RM11 4 mm Oval Precision Optical Performance Best Value AlInGaP and InGaN Lamps Data Sheet



Description

These Precision Optical Performance Oval LEDs are specifically designed for Full Color/Video and Passenger Information signs. The Oval shaped radiation pattern ($60^\circ \times 120^\circ$) and high luminous intensity ensure that these devices are excellent for wide field of view outdoor applications where a wide viewing angle and readability in sunlight are essential. These lamps have very smooth, matched radiation patterns ensuring consistent color mixing in full color applications, message uniformity across the viewing angle of the sign.

High efficiency LED materials are used in these lamps: Higher performance of Aluminum Indium Gallium Phosphide (AlInGaP II) for Red and Amber color and Indium Gallium Nitride (InGaN) for Blue and Green. Each lamp is made with an advanced optical grade epoxy offering superior high temperature and high moisture resistance in outdoor applications. The package epoxy contains both UV-A and UV-B inhibitors to reduce the effects of long term exposure to direct sunlight.

Designers can select parallel or perpendicular orientation. Both lamps are available in tinted version.

Features

- Well-defined spatial radiation pattern
- Viewing angles:
Major axis 120°
Minor axis 60°
- High luminous output
- AlInGaP II (brightest) intensity level
- Colors:
472 nm blue
526 nm green
630 nm red
592 nm amber
- Superior resistance to moisture
- UV resistant epoxy

Benefits

- Viewing angle designed for wide field of view applicaion
- Superior performance in outdoor environments

Applications

- Full color signs

CAUTION: The Blue and Green LEDs are Class 1 ESD sensitive. Please observe appropriate precautions during handling and processing. Refer to Agilent Application Note AN-1142 for additional details.



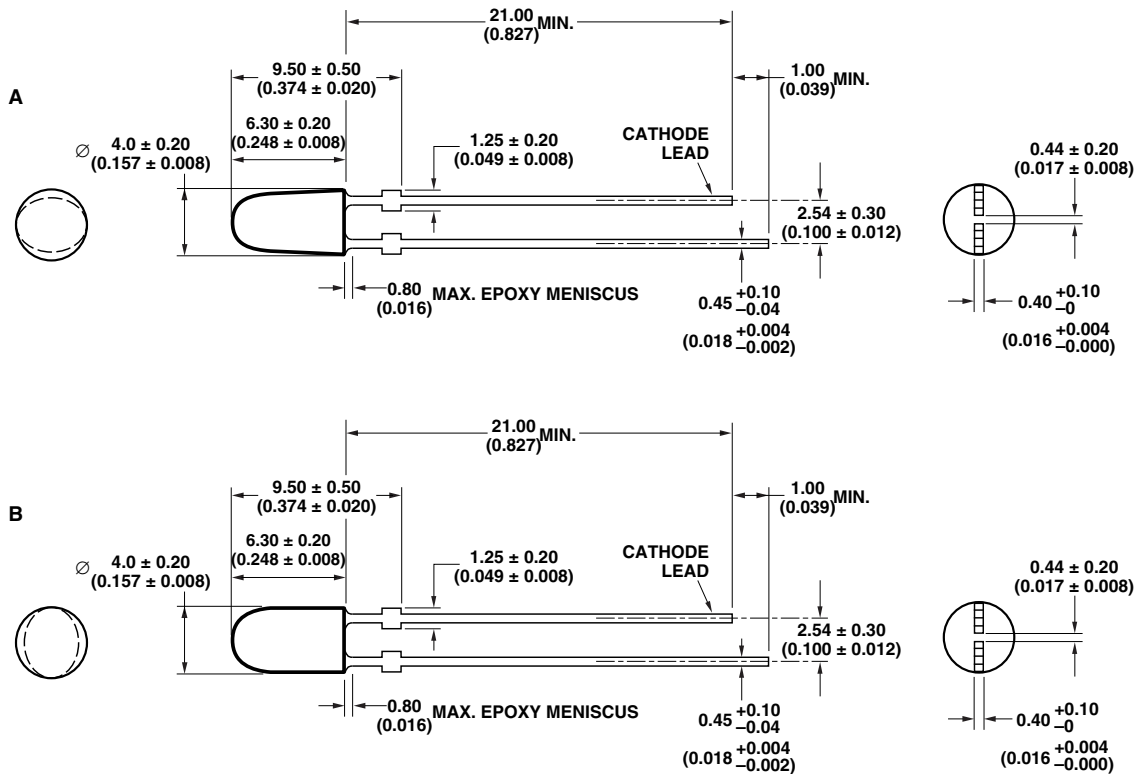
Selection Guide for AlInGaP II

Part Number	Color and Dominant Wavelength λ_d (nm) Typ.	Luminous Intensity, I_v (mcd) Min.	Leads with Stand-Offs	Leadframe Orientation	Package Drawing
HLMP-SL11-H0000	Amber 592	180	Yes	Perpendicular	A
HLMP-RL11-H0000	Amber 592	180	Yes	Parallel	B
HLMP-SD11-J0000	Red 630	240	Yes	Perpendicular	A
HLMP-RD11-J0000	Red 630	240	Yes	Parallel	B

Selection Guide for InGaN

Part Number	Color and Dominant Wavelength λ_d (nm) Typ.	Luminous Intensity, I_v (mcd) Min.	Leads with Stand-Offs	Leadframe Orientation	Package Drawing
HLMP-RB11-D0000	Blue 472	65	Yes	Parallel	B
HLMP-RB11-H0000	Blue 472	180	Yes	Parallel	B
HLMP-RM11-H0000	Green 526	180	Yes	Parallel	B
HLMP-RM11-M0000	Green 526	520	Yes	Parallel	B

Package Dimensions



DIMENSIONS ARE IN MILLIMETERS (INCHES).

Absolute Maximum Ratings at T_A = 25°C

Parameter	Blue and Green	Red and Amber
DC Forward Current ^[1]	30 mA	50 mA
Peak Pulsed Forward Current	100 mA	100 mA
Average Forward Current	30 mA	30 mA
Reverse Voltage (I _R = 100 µA)	5 V	5 V
Power Dissipation	120 mW	120 mW
LED Junction Temperature	100°C	110°C
Operating Temperature Range	–40°C to +80°C	–40°C to +100°C
Storage Temperature Range	–40°C to +100°C	–40°C to +120°C
Wave Soldering Temperature	250°C for 3 sec.	250°C for 3 sec.

Note:

1. Derate linearly as shown in Figure 6 and 7.

Electrical/Optical Characteristics at T_A = 25°C

Parameter	Symbol	Min.	Typ.	Max.	Units	Test Conditions
Typical Viewing Angle						
Major	2θ _{1/2}		120		deg	
Minor			60			
Forward Voltage	V _F					I _F = 20 mA
Amber (λ _d = 592 nm)			2.15	2.5	V	
Red (λ _d = 630 nm)			2.00	2.5		
Blue (λ _d = 472 nm)			3.5	4.0		
Green (λ _d = 526 nm)			3.5	4.0		
Reverse Voltage						
Amber, Red	V _R	5	20		V	I _R = 100 µA
Blue, Green		5	—			I _R = 10 µA
Peak Wavelength						
Amber (λ _d = 592 nm)	λ _{peak}		594		nm	Peak of Wavelength of Spectral Distribution at I _F = 20 mA
Red (λ _d = 630 nm)			639			
Blue (λ _d = 472 nm)			470			
Green (λ _d = 526 nm)			524			
Spectral Halfwidth						
Amber (λ _d = 592 nm)	Δλ _{1/2}		17		nm	Wavelength Width at Spectral Distribution 1/2 Power Point at I _F = 20 mA
Red (λ _d = 630 nm)			17			
Blue (λ _d = 472 nm)			35			
Green (λ _d = 526 nm)			47			
Capacitance						
Amber, Red	C		40		pF	V _F = 0, F = 1 MHz
Blue, Green			43			
Luminous Efficacy						
Amber (λ _d = 592 nm)	η _v		500		lm/W	Emitted Luminous Power/Emitted Radiant Power at I _F = 20 mA
Red (λ _d = 630 nm)			155			
Blue (λ _d = 472 nm)			75			
Green (λ _d = 526 nm)			520			
Thermal Resistance	Rθ _{J-PIN}		240		°C/W	LED Junction-to-Cathode Lead

Notes:

- 2θ_{1/2} is the off-axis angle where the luminous intensity is 1/2 the on-axis intensity.
- The radiant intensity, I_e in watts per steradian, may be found from the equation I_e = I_v/η_v where I_v is the luminous intensity in candelas and η_v is the luminous efficacy in lumens/watt.
- The luminous intensity is measured on the mechanical axis of the lamp package.
- The optical axis is closely aligned with the package mechanical axis.
- The dominant wavelength λ_d is derived from the CIE Chromaticity Diagram and represents the color of the lamp.

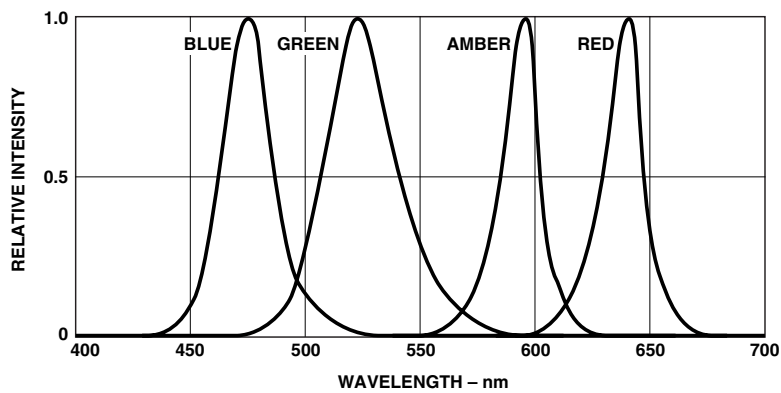


Figure 1. Relative intensity vs. wavelength.

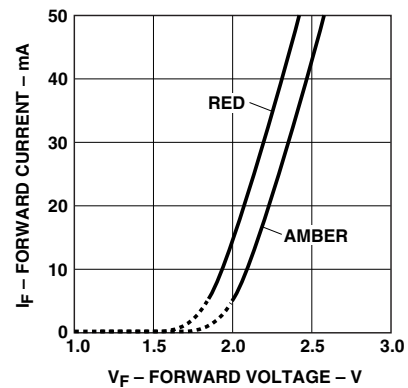


Figure 2. Amber, red forward current vs. forward voltage.

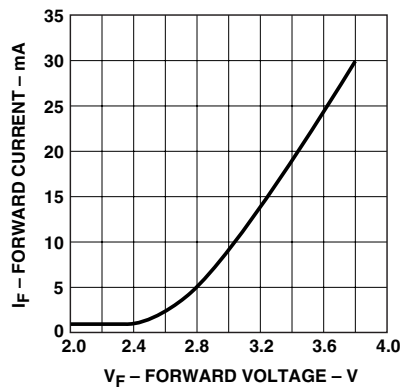


Figure 3. Blue, green forward current vs. forward voltage.

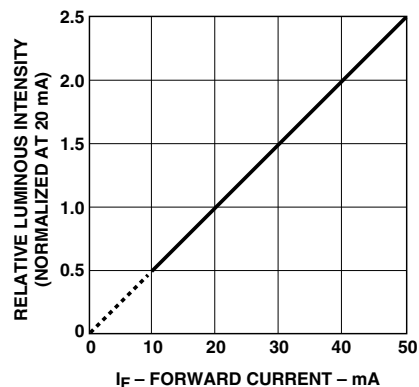


Figure 4. Amber, red relative luminous intensity vs. forward current.

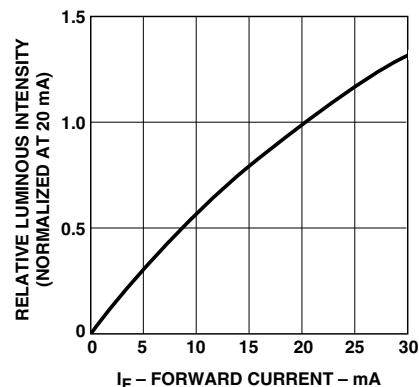


Figure 5. Blue, green relative luminous intensity vs. forward current.

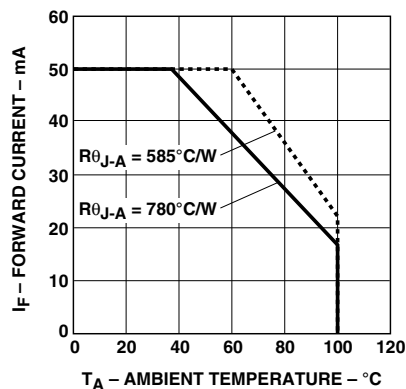


Figure 6. Amber, red maximum forward current vs. ambient temperature.

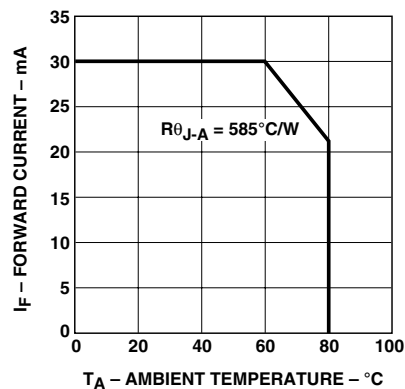


Figure 7. Blue, green maximum forward current vs. ambient temperature.

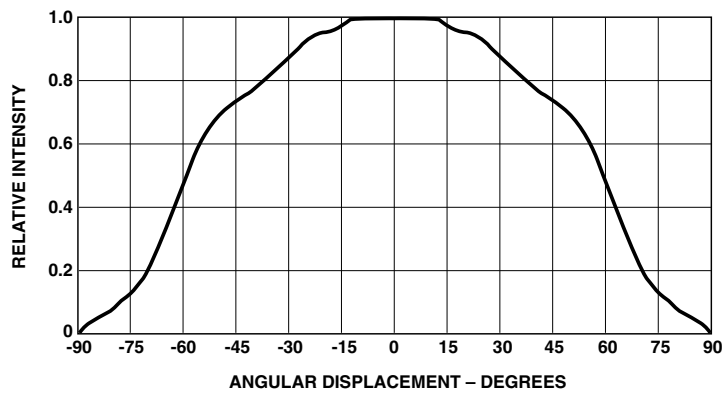


Figure 8a. Representative spatial radiation pattern for major axis.

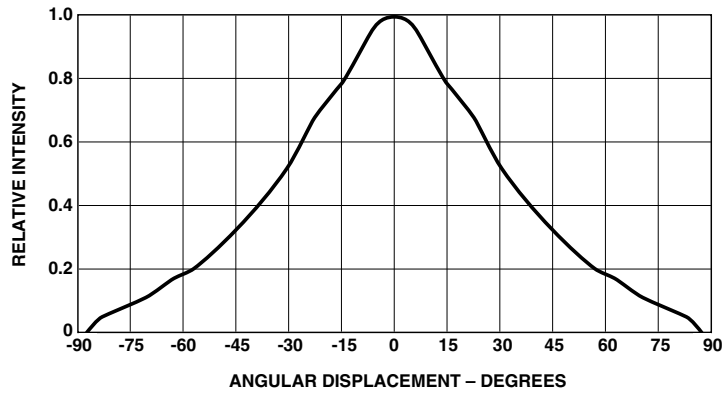


Figure 8b. Representative spatial radiation pattern for minor axis.

Intensity Bin Limits (mcd at 20 mA)

Bin Name	Min.	Max.	Bin Name	Min.	Max.
D	65	85	J	240	310
E	85	110	K	310	400
F	110	140	L	400	520
G	140	180	M	520	680
H	180	240			

Tolerance for each bin limit is $\pm 15\%$.

Note:

1. Bin categories are established for classification of products. Products may not be available in all bin categories.

Color Bin Limits (nm at 20 mA)**Blue**

Bin ID	Color Range (nm)	
	Min.	Max.
1	460.0	464.0
2	464.0	468.0
3	468.0	472.0
4	472.0	476.0
5	476.0	480.0

Tolerance for each bin limit is ± 2 nm.

Green

Bin ID	Color Range (nm)	
	Min.	Max.
1	520.0	524.0
2	524.0	528.0
3	528.0	532.0
4	532.0	536.0
5	536.0	540.0

Tolerance for each bin limit is ± 0.5 nm.

Amber

Bin ID	Color Range (nm)	
	Min.	Max.
1	584.5	587.0
2	587.0	589.5
4	589.5	592.0
6	592.0	594.5

Tolerance for each bin limit is ± 0.5 nm.

Note:

1. All bin categories are established for classification of products. Products may not be available in all bin categories. Please contact your Agilent representatives for further information.

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Data subject to change.

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